

42 V Input Window Voltage Detector

No. EA-405-200904

OVERVIEW

The R3152N is a window voltage detector suited for achieving the functional safety. This device monitors over- and under- voltage of the output voltage from the power supply IC for a microprocessor and a sensor, and can prevent malfunction of system caused by abnormal voltage.

KEY BENEFITS

- A stable voltage with supplying the battery voltage can provide the power supply and the voltage supervising separately.
- High-accuracy detection enables with Overvoltage/Undervoltage Detection Accuracy of -1.25% to 0.75% and Hysteresis of 1.5%
- Small package of SOT-23-6 is adopted, and a safe and secure pin assignment with considering a short among adjacent pins.

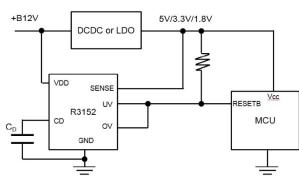
KEY SPECIFICATIONS

- Operating Voltage Range (Max. Rating): 3.0 V to 42.0 V (50.0 V)
- Operating Temperature Range: -40°C to 105°C
- Supply Current: Typ. 1.5 µA
- Overvoltage Detection: 1.1 V to 5.9 V (0.01 V step)
- Undervoltage Detection:1.0 V to 4.8 V (0.01 V step)
- Detection Release Hysteresis: A, Typ. 1.0% with hysteresis
 B, No hysteresis
- Detection Voltage Accuracy:

±0.5% (Ta = 25°C)

- -1.25% to 0.75% (-40°C ≤ Ta ≤ 105°C)
- Release Output Delay Time: Typ. 4 ms (C_D = 0.01 μF)
- Output Type: Nch. Open Drain

TYPICAL APPLICATIONS



 $C_{\ensuremath{\mathsf{D}}}$: a capacitor set according to the release delay times

APPLICATIONS

- Power Supply Voltage Monitoring for Laptop PCs, Digital TVs, Cordless Phones and Private LAN Systems
- Power Supply Voltage Monitoring for Multi-cell Battery Using Devices

SELECTION GUIDE

Product Name	Package	Quantity per Reel
R3152Nxxx\$-TR-FE	SOT-23-6	3,000 pcs

xxx: The combination of an overvoltage detection

setting voltage (VOVSET) and an undervoltage

detection setting voltage (VUVSET)

Refer to *Product-specific Electrical Characteristics* for more details.

\$: Hysteresis

\$	Hysteresis					
Α	Yes					
В	No					

PACKAGE



SOT-23-6 2.9 x 2.8 x 1.1 (mm)

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SELECTION GUIDE

The overvoltage detection setting voltage (V_{OVSET}) and the undervoltage detection setting voltage (V_{UVSET}) are user-selectable options.

Selection Guide

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R3152Nxxx\$-TR-FE	SOT-23-6	3,000 pcs	Yes	Yes

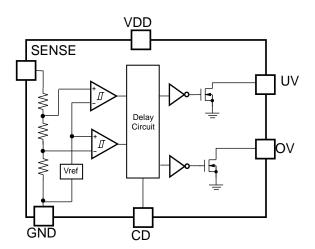
xxx: The combination of an overvoltage detection setting voltage (V_{OVSET}) and an undervoltage detection setting voltage (V_{UVSET}).

Refer to *Product-specific Electrical Characteristics* for more details.

\$: Hysteresis

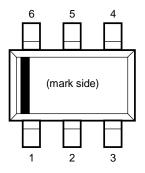
\$	Hysteresis
А	Yes
В	No

BLOCK DIAGRAM



R3152N Block Diagram

PIN DESCRIPTIONS



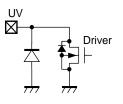
SOT-23-6 Pin Configuration

Pin Description

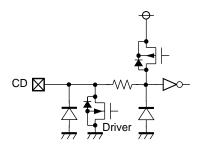
Pin No.	Symbol	Description
1	VDD	Supply Voltage Pin
2	CD	VD Release Delay Time Set Pin (for connecting with external capacitor for delay)
3	UV	Undervoltage Detection Output Pin ("Low" at detection)
4	OV	Overvoltage Detection Output Pin ("Low" at detection)
5	GND	GND Pin
6	SENSE	SENSE Pin

Internal Equivalent Circuit for Each Pin

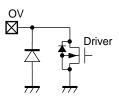
UV Pin



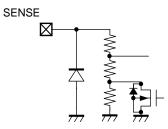
CD Pin



OV Pin



SENSE Pin



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ABSOLUTE MAXIMUM RATINGS

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
M	Supply Voltage	-0.3 to 50.0	V
Vdd	Peak Voltage ⁽¹⁾	60	V
Vcd	CD Pin Output Voltage	-0.3 to 50.0	V
Vuvout	UV Pin Output Voltage	-0.3 to 7.0	V
Vovout	OV Pin Output Voltage	-0.3 to 7.0	V
VSENSE	SENSE Pin Input Voltage	-0.3 to 7.0	V
Ιυνουτ	UV Pin Output Current	30	mA
Ιονουτ	OV Pin Output Current	30	mA
PD	Power Dissipation ⁽²⁾ (SOT-23-6, JEDEC STD.51-7)	660	mW
Tj	Junction Temperature Range	-40 to 125	°C
Tstg	Storage Temperature Range	-55 to 125	°C

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings are not assured.

RECCOMENDED OPERATING CONDITIONS

Recommended Operating Conditions

Symbol	Parameter	Rating	Unit
Vdd	Operating Voltage	3.0 to 42	V
V _{SENSE}	SENSE Pin Input Voltage	0 to 6.0	V
Та	Operating Temperature Range	-40 to 105	°C

RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if they are used over such ratings by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

⁽¹⁾ Duration Time: 200 ms

⁽²⁾ Refer to POWER DISSIPATION for detailed information.

ELECTRICAL CHARACTERISTICS

 V_{DD} = 14 V, C_D = 0.01 µF, pulled-up to 5 V with 100 k Ω , unless otherwise specified.

The specifications surrounded by are guaranteed by design engineering at $-40^{\circ}C \le Ta \le 105^{\circ}C$.

Symbol	Parameter	Test Conditions/Comments	Min.	Тур.	Max.	Unit
M	Overvoltage (OV) Detector	Ta = 25°C	x0.995		x1.005	V
Vovdet	Threshold	–40°C ≤ Ta ≤ 105°C	x0.9875		x1.0075	V
M	Undervoltage (UV) Detector	Ta = 25°C	x0.995		x1.005	V
VUVDET	Threshold	–40°C ≤ Ta ≤ 105°C	x0.9875		x1.0075	V
V _{OVHYS}	Overvoltage (OV) Threshold	With Hysteresis	V _{OVDET} ×0.005	V _{OVDET} ×0.01	V _{OVDET} ×0.015	V
	Hysteresis	No Hysteresis	0		10	mV
Vuvhys	Undervoltage (UV)	With Hysteresis	V _{UVDET} ×0.005	V _{UVDET} ×0.01	V _{UVDET} ×0.015	V
	Threshold Hysteresis	No Hysteresis	0		10	mV
lss	Consumption Current	VUVDET < SENSE < VOVDET		1.5	3.2	μΑ
RSENSE	SENSE Pin Resistance		7	14	28	MΩ
V_{UVLO}	UVLO Detector Threshold			1.8	2.8	V
VUVLOHYS	UVLO Threshold Hysteresis			0.1	0.2	V
Vovout	Overvoltage (OV) pulled-up output voltage				6.0	V
Vuvout	Undervoltage (UV) pulled-up output voltage				6.0	V
VDDLOV	Overvoltage (OV) Low-operating Voltage ⁽¹⁾				1.7	V
Vddluv	Undervoltage (UV) Low-operating Voltage ⁽¹⁾				1.7	V
IOUT	OV Pin Nch. Driver Output Current	$V_{DD} = 3.0, V_{DS} = 0.1 V$	0.8	1.8		mA
IOUT	UV Pin Nch. Driver Output Current	V_{DD} = 3.0, V_{DS} = 0.1 V	0.8	1.8		mA
l	OV Pin Nch.Driver Leak Current	$V_{OVOUT} = 5.5 V$			0.3	μA
ILEAK	UV Pin Nch Driver Leak Current	Vuvout = 5.5 V			0.3	μA
t DELAY	Release Delay Time		2.5	4	8	ms

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj \approx Ta = 25°C).

 $^{^{(1)}}$ Minimum value of power supply voltage when an output voltage will become less than 0.1V at detection. (pulled-up resistance: 100 k Ω , pulled-up voltage: 5 V)

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 $V_{\text{DD}} = 14 \text{ V}, C_{\text{D}} = 0.01 \text{ }\mu\text{F}, \text{ pulled-up to 5 V with 100 k}\Omega, \text{ unless otherwise specified.}$ The specifications surrounded by ______ are guaranteed by design engineering at -40°C ≤ Ta ≤ 105°C.

(Ta = 25°C)

Product	JCt VOVDET (V)		V	UVDET ()	/)	١	Vovers (V)	VUVHYS (V)			
name	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.
R3152N001A	5.27350	5.30	5.32650	4.67650	4.70	4.72350	0.02650	0.05300	0.07950	0.02350	0.04700	0.07050
R3152N002A	3.52230	3.54	3.55770	3.03475	3.05	3.06525	0.01770	0.03540	0.05310	0.01525	0.03050	0.04575
R3152N003B	3.55215	3.57	3.58785	2.48750	2.50	2.51250	0	-	0.01000	0	-	0.01000
R3152N004A	1.86065	1.87	1.87935	1.73130	1.74	1.74870	0.00935	0.01870	0.02805	0.00870	0.01740	0.02610
R3152N005A	3.41285	3.43	3.44715	3.17405	3.19	3.20595	0.01715	0.03430	0.05145	0.01595	0.03190	0.04785
R3152N013A	1.32335	1.33	1.33665	1.16415	1.17	1.17585	0.00665	0.01330	0.01995	0.00585	0.01170	0.01755
R3152N014A	1.16415	1.17	1.17585	1.06963	1.075	1.08037	0.00585	0.01170	0.01755	0.00538	0.01075	0.01613
R3152N015A	1.28355	1.29	1.29645	1.15420	1.16	1.16580	0.00645	0.01290	0.01935	0.00580	0.01160	0.01740
R3152N017A	3.55215	3.57	3.58785	2.72630	2.74	2.75370	0.01785	0.03570	0.05355	0.01370	0.02740	0.04110
R3152N020A	1.24375	1.25	1.25625	1.11440	1.12	1.12560	0.00625	0.01250	0.01875	0.00560	0.01120	0.01680
R3152N201B	1.23380	1.24	1.24620	1.16415	1.17	1.17585	0	-	0.01000	0	-	0.01000
R3152N101B	2.58700	2.60	2.61300	2.39795	2.41	2.42205	Ō	-	0.01000	Ō	-	0.01000
R3152N102B	3.41285	3.43	3.44715	3.16410	3.18	3.19590	Ō	-	0.01000	Ō	-	0.01000
R3152N203A	1.39300	1.40	1.40700	0.99500	1.00	1.00500	0.00700	0.01400	0.02100	0.00500	0.01000	0.01500
R3152N204A	1.62185	1.63	1.63815	1.40295	1.41	1.41705	0.00815	0.01630	0.02445	0.00705	0.01410	0.02115
R3152N103A	5.77100	5.80	5.82900	4.75610	4.78	4.80390	0.02900	0.05800	0.08700	0.02390	0.04780	0.07170
R3152N104A	3.38300	3.40	3.41700	1.59200	1.60	1.60800	0.01700	0.03400	0.05100	0.00800	0.01600	0.02400

R3152N Product-specific Electrical Characteristics

RICOH

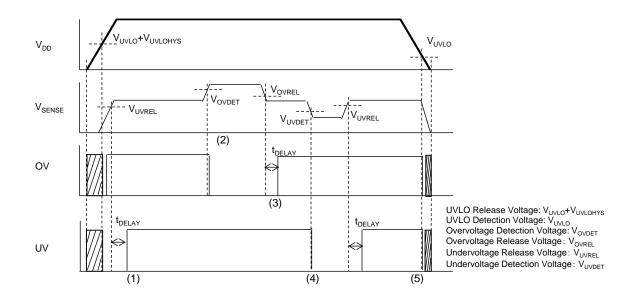
No. EA-405-200904

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(-40°C ≤ Ta ≤ 105°C)

Product	VOVDET (V)		v	VUVDET (V)			Vovnys (V)	VUVHYS (V)			
name	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.
R3152N001A	5.23375	5.30	5.33975	4.64125	4.70	4.73525	0.02650	0.0530	0.07950	0.02350	0.04700	0.07050
R3152N002A	3.49575	3.54	3.56655	3.01188	3.05	3.07287	0.01770	0.0354	0.05310	0.01525	0.03050	0.04575
R3152N003B	3.52538	3.57	3.59678	2.46875	2.50	2.51875	0	-	0.01000	0	-	0.01000
R3152N004A	1.84663	1.87	1.88403	1.71825	1.74	1.75305	0.00935	0.01870	0.02805	0.00870	0.01740	0.02610
R3152N005A	3.38713	3.43	3.45573	3.15013	3.19	3.21392	0.01715	0.03430	0.05145	0.01595	0.0319	0.04785
R3152N013A	1.31338	1.33	1.33997	1.15538	1.17	1.17877	0.00665	0.01330	0.01995	0.00585	0.01170	0.01755
R3152N014A	1.15537	1.17	1.17878	1.06156	1.075	1.08307	0.00585	0.01170	0.01755	0.00538	0.01075	0.01613
R3152N015A	1.27387	1.29	1.29968	1.14550	1.16	1.16870	0.00645	0.01290	0.01935	0.00580	0.01160	0.01740
R3152N017A	3.52537	3.57	3.59678	2.70575	2.74	2.76055	0.01785	0.03570	0.05355	0.01370	0.02740	0.04110
R3152N020A	1.23438	1.25	1.25937	1.10600	1.12	1.12840	0.00625	0.01250	0.01875	0.00560	0.01120	0.01680
R3152N201B	1.22450	1.24	1.24930	1.15538	1.17	1.17877	0	-	0.01000	0	-	0.01000
R3152N101B	2.56750	2.60	2.61950	2.37988	2.41	2.42807	0	-	0.01000	0	-	0.01000
R3152N102B	3.38713	3.43	3.45572	3.14025	3.18	3.20385	0	-	0.01000	0	-	0.01000
R3152N203A	1.38250	1.40	1.41050	0.98750	1.00	1.00750	0.00700	0.01400	0.02100	0.00500	0.01000	0.01500
R3152N204A	1.60963	1.63	1.64222	1.39238	1.41	1.42057	0.00815	0.01630	0.02445	0.00705	0.01410	0.02115
R3152N103A	5.72750	5.80	5.84350	4.72025	4.78	4.81585	0.02900	0.05800	0.08700	0.02390	0.04780	0.07170
R3152N104A	3.35750	3.40	3.42550	1.58000	1.60	1.61200	0.01700	0.03400	0.05100	0.00800	0.01600	0.02400

THEORY OF OPERATION



R3152N Timing Chart

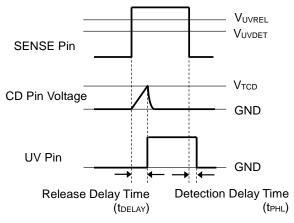
- (1) When the SENSE pin voltage (V_{SENSE}) exceed the undervoltage release voltage (V_{UVREL}), the UV pin output becomes "High" after the release delay time (t_{DELAY}).
- (2) When V_{SENSE} exceed the overvoltage detection voltage (V_{OVDET}) by increasing in voltage, the OV pin output becomes "Low" after the detection delay time (Typ.10 μs) and enters the overvoltage detecting state.
- (3) When V_{SENSE} decreases less than the overvoltage release voltage (V_{OVREL}), the OV pin output becomes "High" after the release delay time (t_{DELAY}).
- (4) When V_{SENSE} decreases less than the undervoltage detection voltage (V_{UVDET}), the UV pin output becomes "Low" after the detection delay time (Typ.10 μs).
- (5) When the VDD pin voltage (V_{DD}) decreases less than the UVLO detection voltage (V_{UVLO}), the OV and UV pins output become "Low".

Note: A certain tilting angle of power supply voltage of the R3152NxxxB may cause chattering at detection or at release. To prevent the occurrence of chattering, connect a 10-nF or more capacitor to the CD pin.

Delay Operation and Delay Time (t_{DELAY})

At Undervoltage Detection

When supplying a voltage higher than the undervoltage release voltage (V_{UVREL}) to the SENSE pin, a charging to an external capacitor starts and the CD pin voltage (V_{CD}) increases. The UV pin voltage (V_{UV}) maintains "Low" until V_{CD} reaches the CD pin threshold voltage (V_{TCD}). When V_{CD} exceeds V_{TCD} , V_{UV} is inverted from "Low" to "High". The release delay time (t_{DELAY}) is the period from the SENSE pin voltage (V_{SENSE}) exceeds V_{UVREL} to a rising edge of V_{UV} . When the output voltage turns from "Low" to "High", a charge carrier of the external capacitor starts discharging. When the voltage lower than V_{UV} is supplied to the SENSE pin, the detection delay time (t_{PHL}), which is the period that V_{UV} is inverted from "High" to "Low", remains constant independent of the external capacitor.



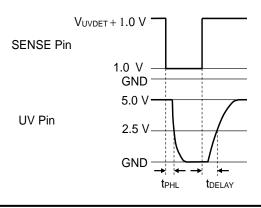
Undervoltage Release Delay Timing Diagram

Calculation of Release Delay Time (t_{DELAY})

The following equation can calculate a typical value of the release delay time (t_{DELAY}) with using the external capacitor (C_D).

 t_{DELAY} (s) = 0.73 × C_D (F) / (1.5×10⁻⁶)

 t_{DELAY} is the period from supplying a pulse voltage of 1.0 V \rightarrow (V_{UVDET}) + 1.0 V to the SENSE pin to the UV pins reached 2.5 V.

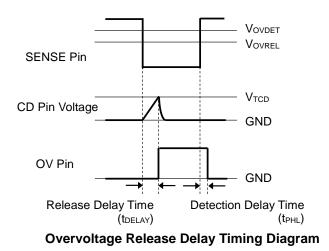


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At Overvoltage Detection

When supplying a voltage lower than the overvoltage release voltage (V_{OVREL}) to the SENSE pin, a charging to an external capacitor starts and the CD pin voltage (V_{CD}) increases. The OV pin voltage (V_{OV}) maintains "Low" until VCD reaches the CD pin threshold voltage (V_{TCD}). When V_{CD} exceeds V_{TCD} , V_{OV} is inverted from "Low" to "High". The release delay time (t_{DELAY}) is the period from the SENSE pin voltage (V_{SENSE}) falls below V_{OVREL} to a rising edge of V_{OV} . When the output voltage turns from "Low" to "High", a charge carrier of the external capacitor starts discharging. When the voltage higher than V_{OV} is supplied to the SENSE pin, the detection delay time (t_{PHL}), which is the period that V_{OV} is inverted from "High" to "Low", remains constant independent of the external capacitor.

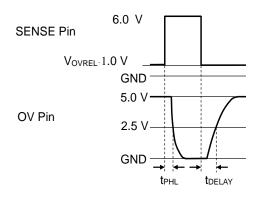


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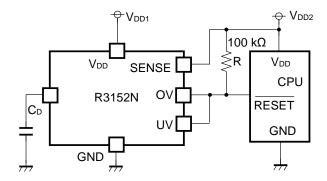
 t_{DELAY} (s) = 0.73 × C_D (F) / (1.5×10⁻⁶)

t_{DELAY} is the period from supplying a pulse voltage of 1.0 V \rightarrow (V_{OVREL}) + 1.0 V to the SENSE pin to the OV pin reached 2.5 V after the OV pin is pulled up to 5V by connecting with a resistor of 100k Ω .





APPLICATION INFORMATION



R3152N Typical Application Circuit

Recommended External Components

Symbol	Description
<u> </u>	A capacitor corresponding to setting of Release Delay Time is required. Refer to "Delay in
CD	Operation and Released Delay Time (t _{DELAY})" in Operation Description for details.
	A resistor is required to set with consideration of the output current at Nch. driver's ON and the
R1	leakage current at Nch. driver's OFF. Refer to "Electrical Characteristic" for details - provided
	the evaluation result with using a resistor of 100 k Ω .

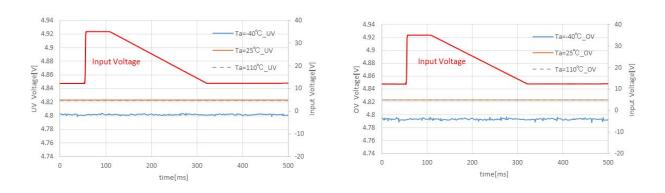
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TYPICAL CHARACTERISTICS

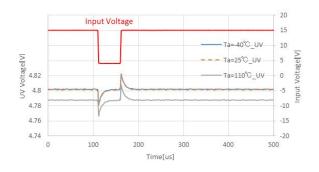
Typical Characteristics are intended to be used as reference data, they are not guaranteed.

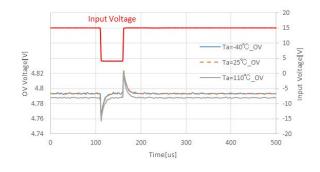
1) Load Dump

VUVSET = 3.0 V, VOVSET = 3.6 V, VSENSE = 3.3 V, Pulled-up to 5.0 V

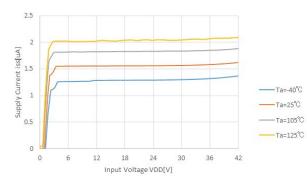


2) Cold Crank $V_{\text{UVSET}} = 3.0 \text{ V}, V_{\text{OVSET}} = 3.6 \text{ V}, V_{\text{SENSE}} = 3.3 \text{ V}, \text{Pulled-up to } 5.0 \text{ V}$

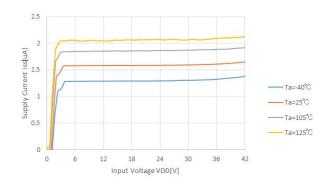






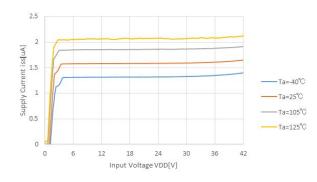


 V_{UVSET} = 3.0 V, V_{OVSET} = 3.6 V

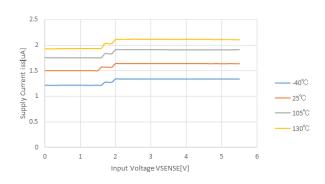


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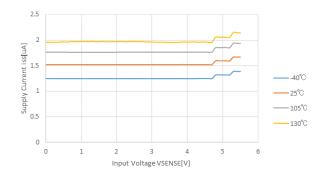
 $V_{UVSET} = 4.7 \text{ V}, V_{OVSET} = 5.3 \text{ V}$



4) Supply Current vs. V_{SENSE} VUVSET = 1.6 V, VOVSET = 2.0 V

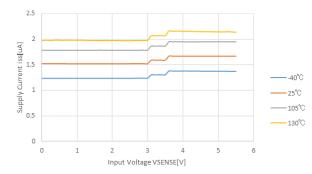


 V_{UVSET} = 4.7 V, V_{OVSET} = 5.3 V



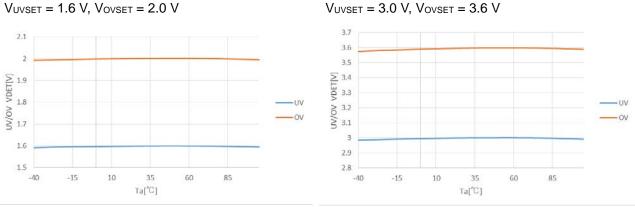
 $V_{UVSET} = 3.0 \text{ V}, V_{OVSET} = 3.6 \text{ V}$

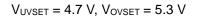
RICOH

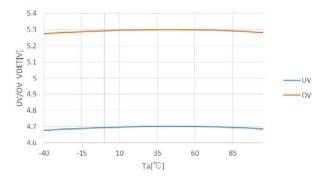


No. EA-405-200904

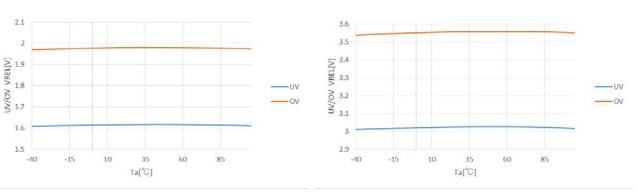
5) UV/OV Detection Voltage vs. Ambient Temperature





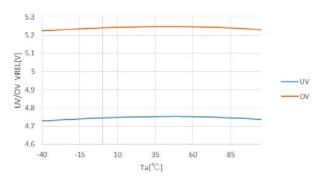


6) UV/OV Release Voltage vs. Ambient Temperature VUVSET = 1.6 V, VOVSET = 2.0 V VUVSET = 3.0 V, VOVSET = 3.6 V

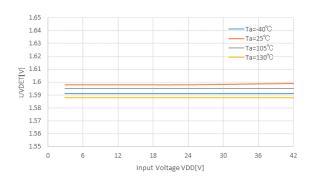


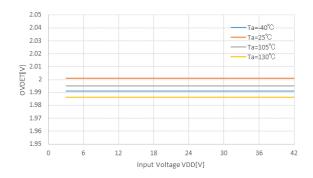
No. EA-405-200904

 $V_{UVSET} = 4.7 V$, $V_{OVSET} = 5.3 V$

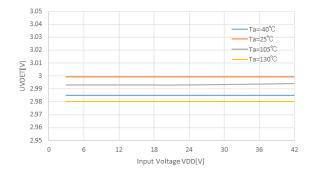


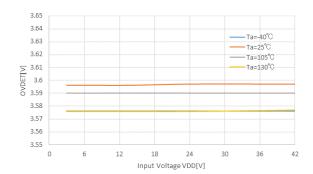
7) UV/OV Detection Voltage vs. V_{DD} VUVSET = 1.6 V, VOVSET = 2.0 V





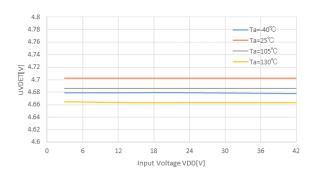
 $V_{UVSET} = 3.0 \text{ V}, V_{OVSET} = 3.6 \text{ V}$

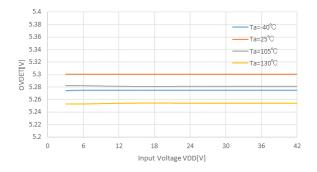




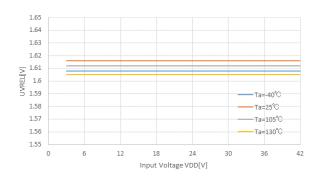
No. EA-405-200904

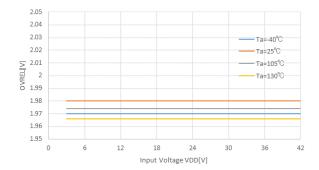
 $V_{UVSET} = 4.7 \text{ V}, V_{OVSET} = 5.3 \text{ V}$



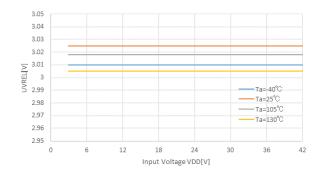


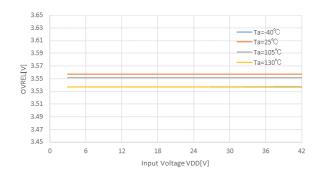
8) UV/OV Release Voltage vs. V_{DD} V_{UVSET} = 1.6 V, V_{OVSET} = 2.0 V





 $V_{UVSET} = 3.0V, V_{OVSET} = 3.6 V$

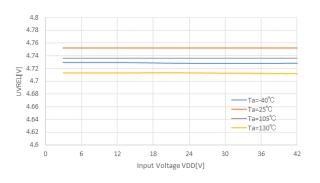


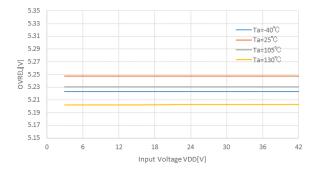




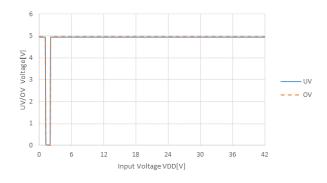
No. EA-405-200904

 $V_{UVSET} = 4.7 \text{ V}, V_{OVSET} = 5.3 \text{ V}$

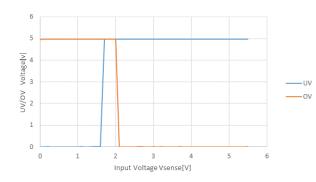




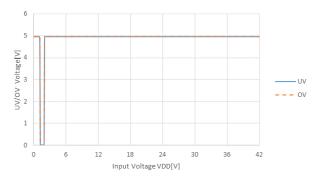




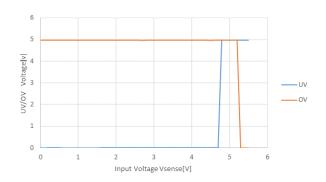
10) UV/OV Voltage vs. V_{SENSE} (Ta = 25°C) $V_{UVSET} = 1.6 V$, $V_{OVSET} = 2.0 V$



 $V_{UVSET} = 4.7 \text{ V}, V_{OVSET} = 5.3 \text{ V}$



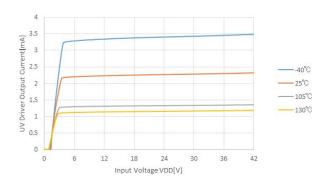
 $V_{UVSET} = 4.7 V$, $V_{OVSET} = 5.3 V$

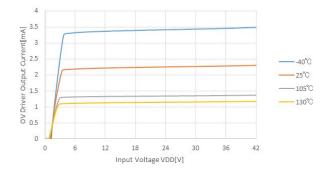


No. EA-405-200904

11) Driver Output Current vs. V_{DD}

 $V_{UVSET} = 4.7 V$, $V_{OVSET} = 5.3 V$





Vin=3V

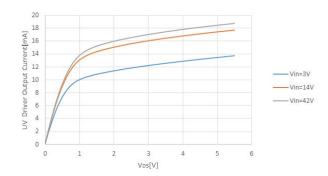
Vin=14V

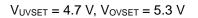
5

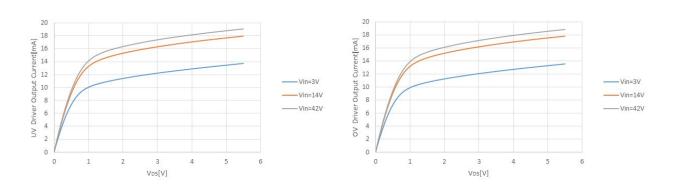
6

-Vin=42V

12) Driver Output Current vs. V_{DS} (Ta = 25°C) VUVSET = 1.6 V, VOVSET = 2.0 V







20

18

2

0

0

1

2

3

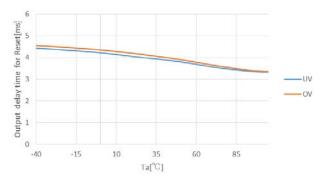
VDS[V]

4

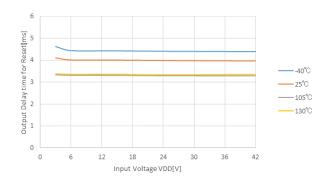
No. EA-405-200904

13) Release Delay Time vs. Ambient Temperature

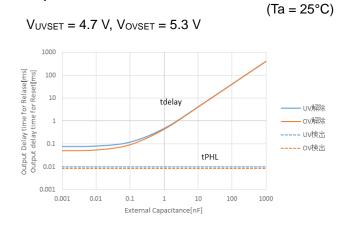
 $V_{UVSET} = 4.7 V$, $V_{OVSET} = 5.3 V$

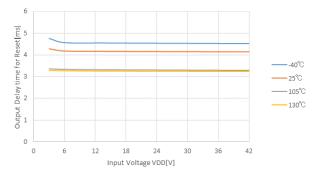


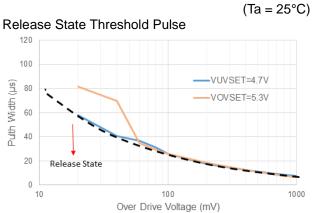
14) Release Delay Time vs. V_{DD} VUVSET = 4.7 V, VOVSET = 5.3 V



15) Detection / Release Delay Time vs. External 16) SENSE Pulse Width vs. One Drive Voltage Capacitor for CD Pin







POWER DISSIPATION

SOT-23-6

 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

Item	Measurement Conditions	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)	
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm	
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square	
Through-holes	φ 0.3 mm × 7 pcs	

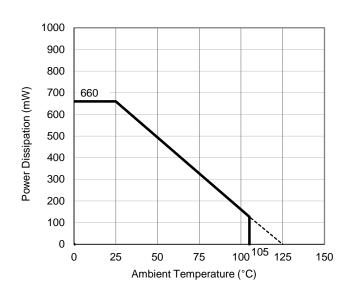
Measurement Conditions

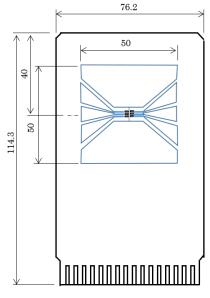
Measurement Result

Item	Measurement Result
Power Dissipation	660 mW
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

θja: Junction-to-Ambient Thermal Resistance

wit: Junction-to-Top Thermal Characterization Parameter





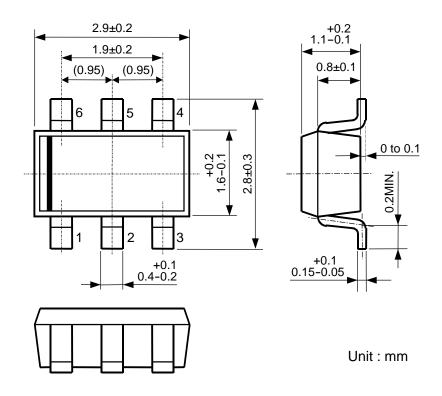
Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

PACKAGE DIMENSIONS

SOT-23-6

Ver. A





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